

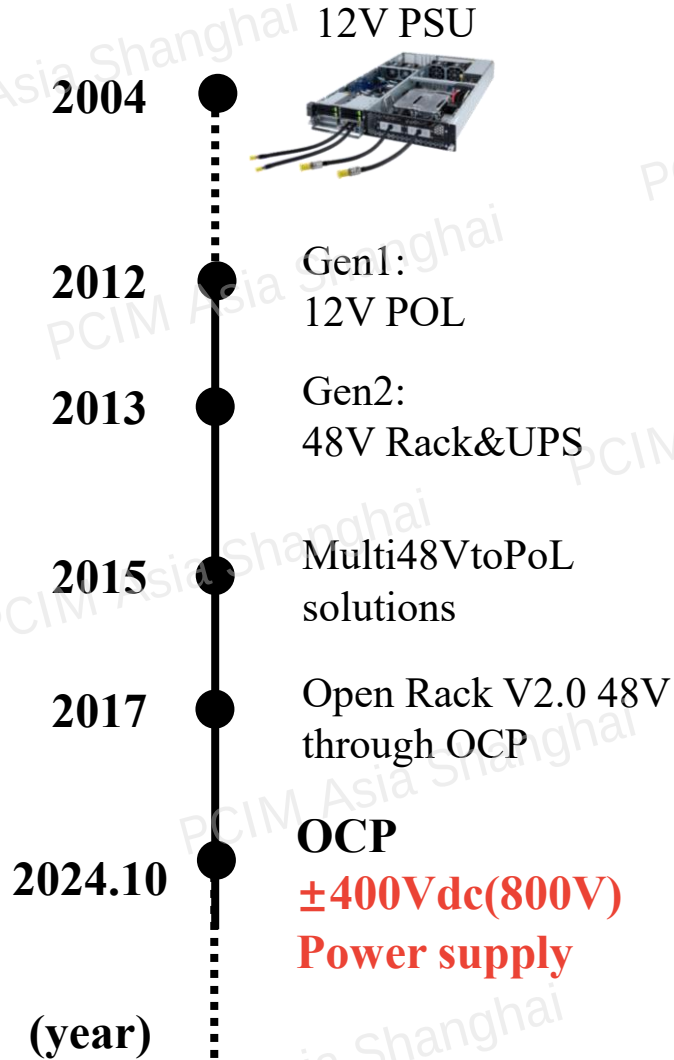
High Efficiency and High Power Density Three-phase MISN-PFC with Wide DC Bus

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Server Power Architecture Develops towards $\pm 400\text{V}(800\text{V})$



Grid
10kV/13.8kV/
20kV/34.5kV

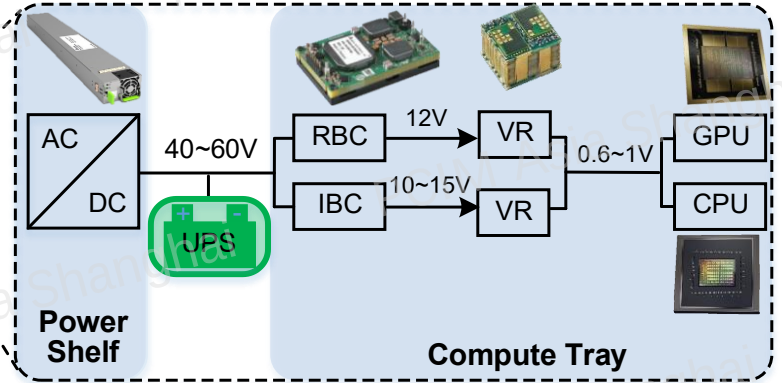


400VAC

■ Today



Server Rack



■ $\pm 400\text{V}(800\text{V})$ Architecture

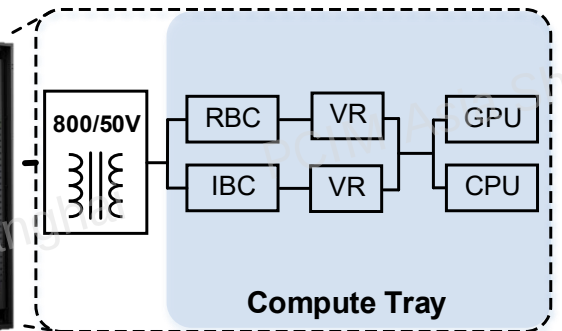


Sidecar Rack

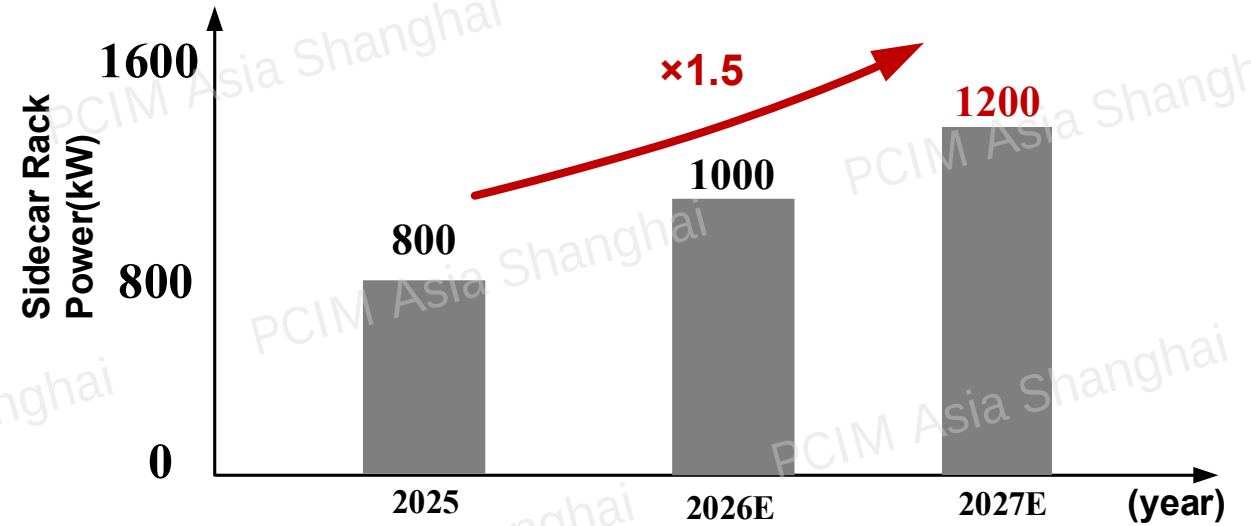
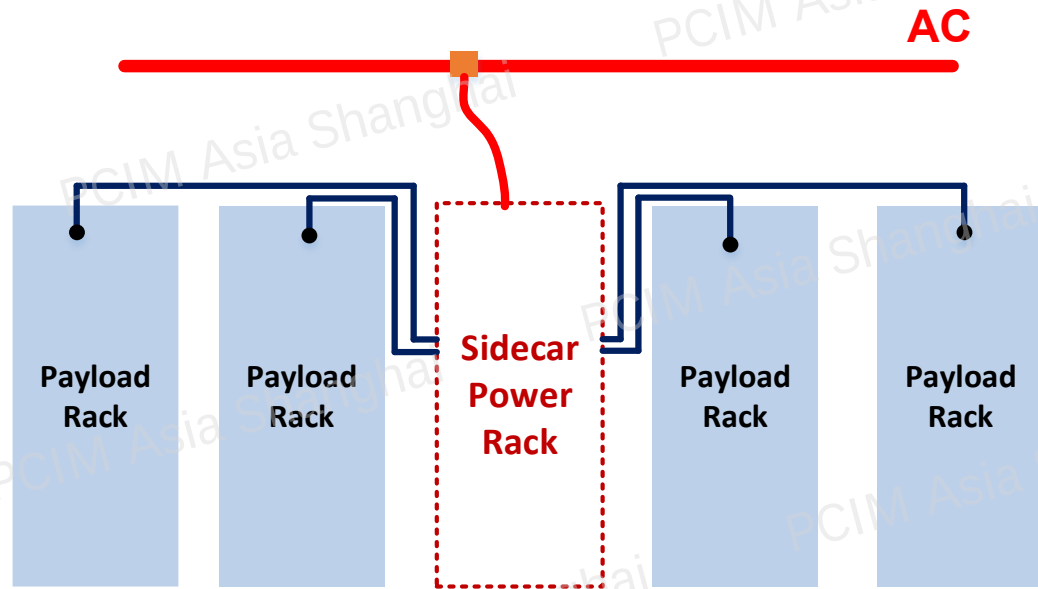
$\pm 400\text{V}$
(800V)



Server Rack



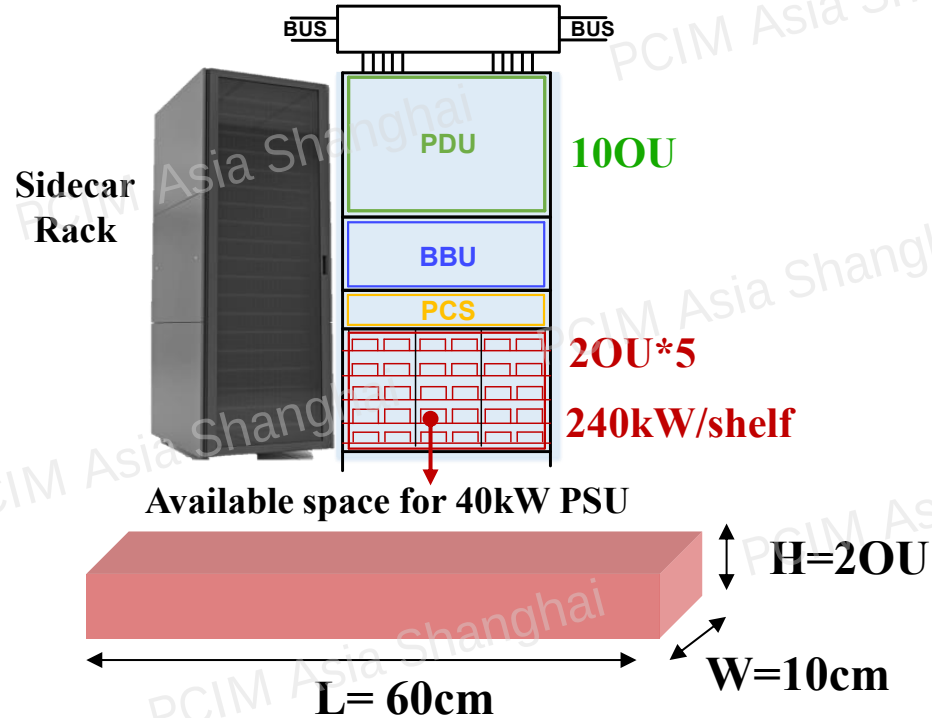
Trend of Sidecar Rack Power



The power of server rack has been rapidly increasing

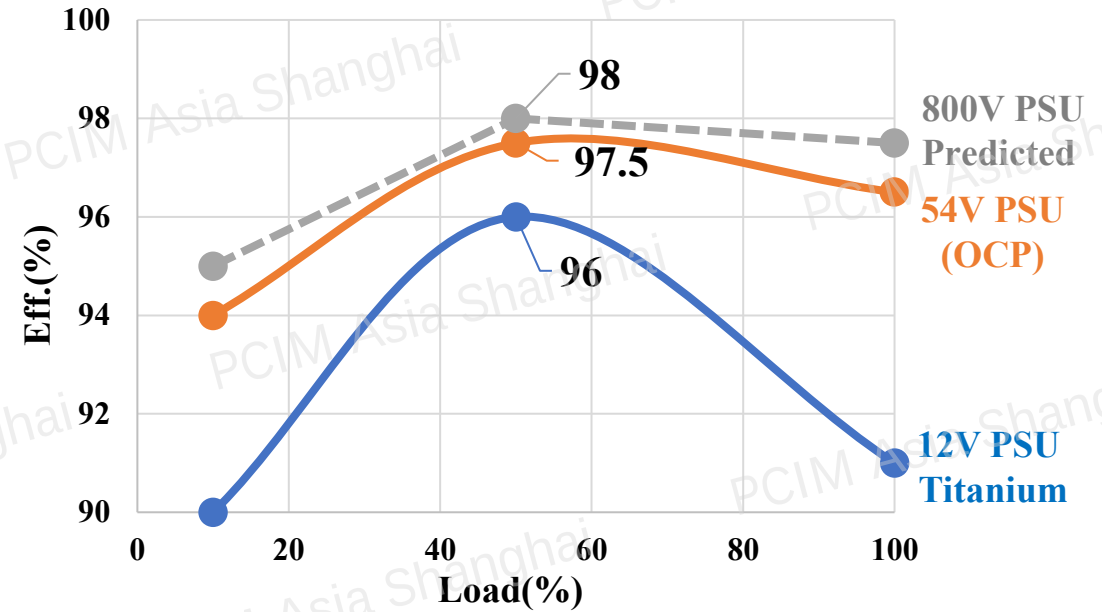
High Efficiency High Density for Server PSU

➤ High Power Density



Power Density: >150W/in³

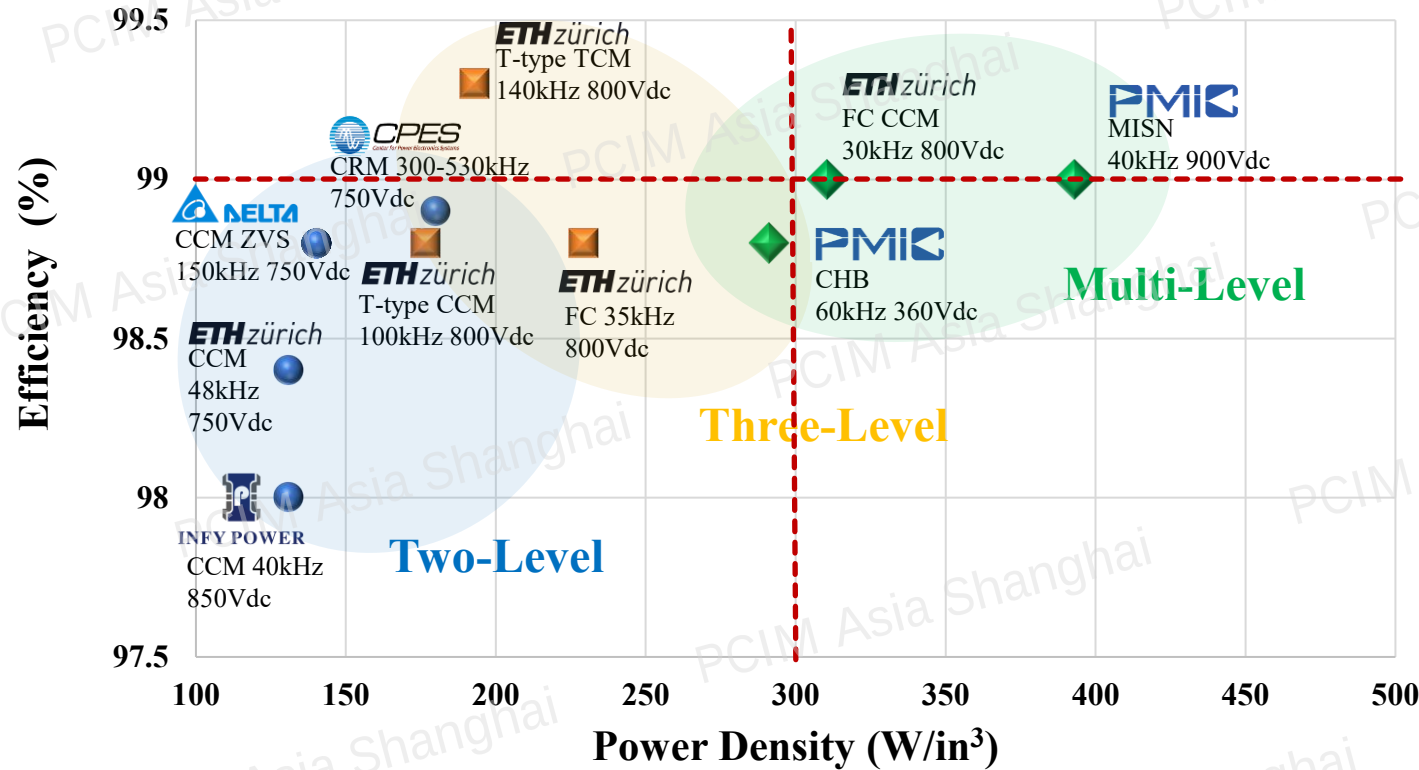
➤ High Efficiency



Efficiency: >98%

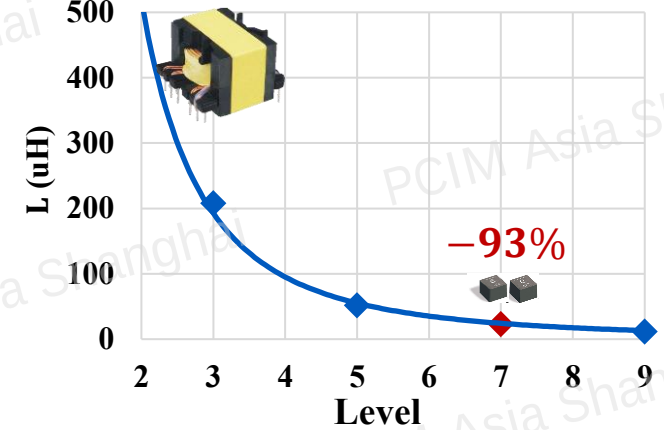
Comparison the Different Multilevel Topologies

Power density: $> 300\text{W/in}^3$
Efficiency: $> 99\%$

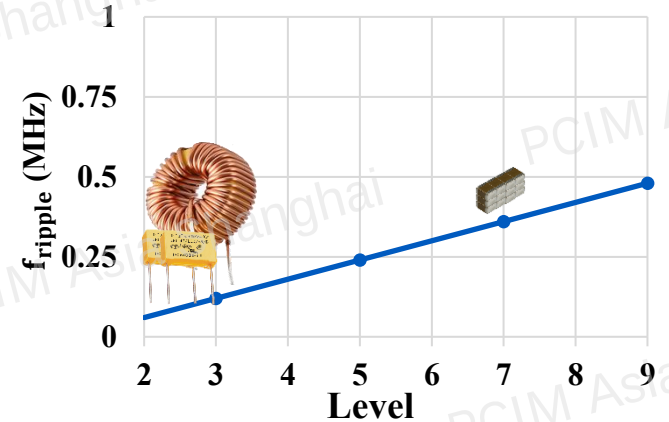


➤ The Influence of Multilevel Converter

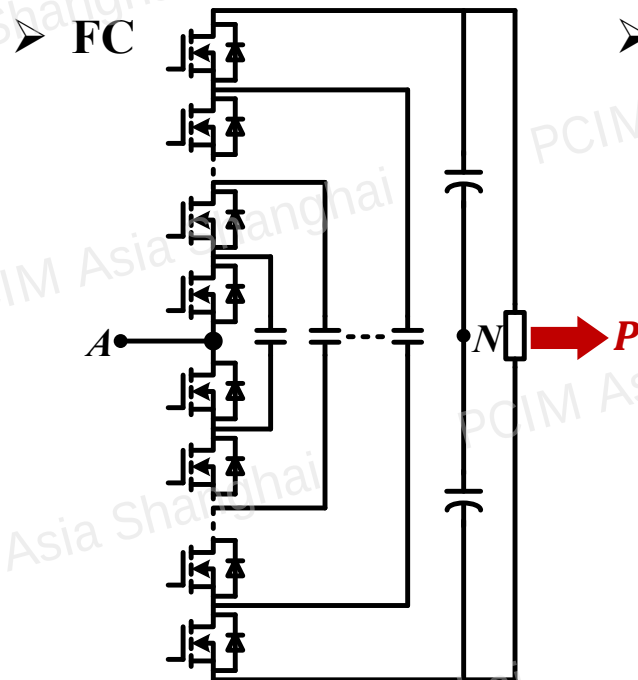
• Lower Volt-second



• Higher Frequency



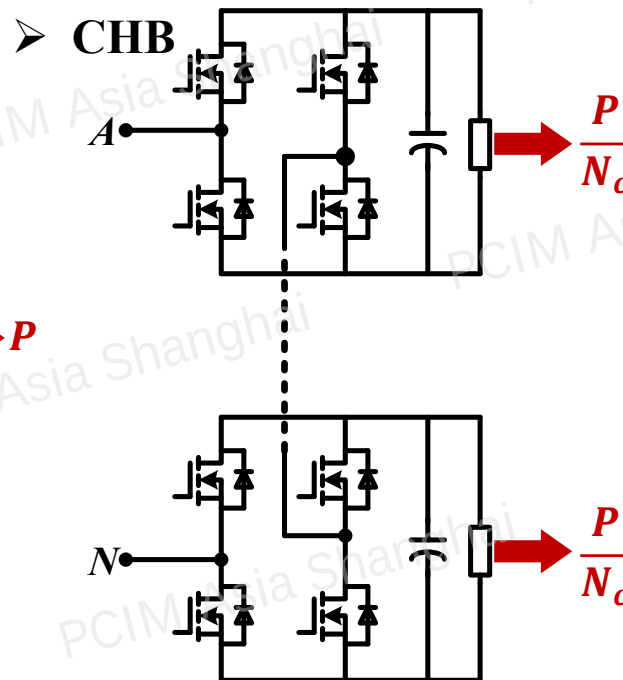
Comparison the Different Multilevel Topologies



✓ **Single DC Bus**

✗ **Bad Modularity**

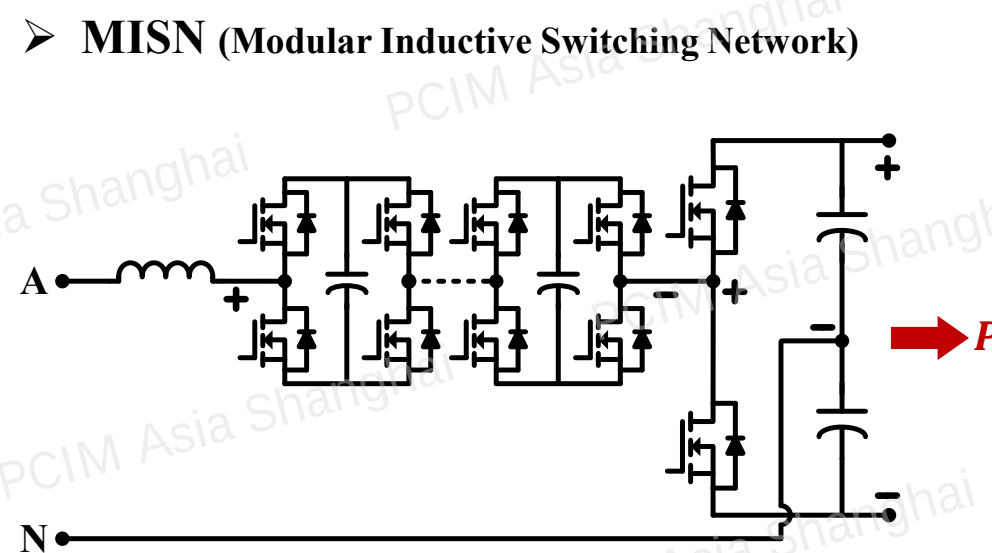
Short fault protect
Redundancy



✓ **Good Modularity**

✗ **Multiple DC Bus**

Complicated structure
Bulky Capacitor



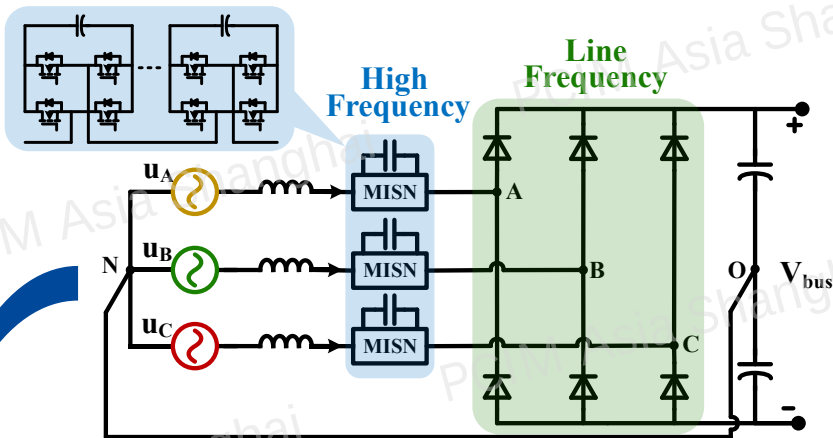
✓ **Single DC Bus**

✓ **Good Modularity**

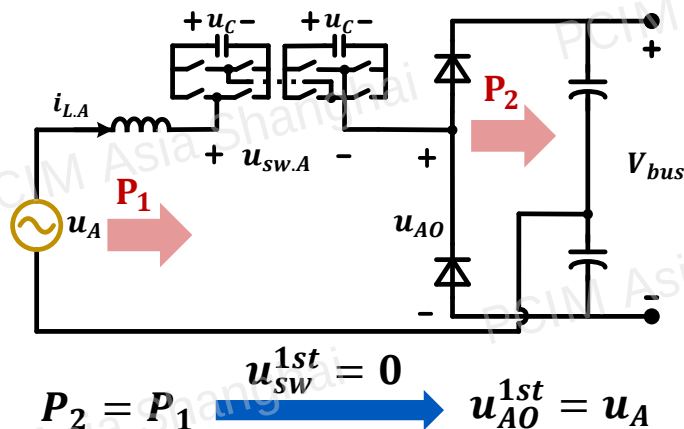
✗ **Line-frequency Bridge**

Operating Principle of Diode-Based MISN Converter (Unregulated)

➤ Diode-Based MISN-PFC Converter

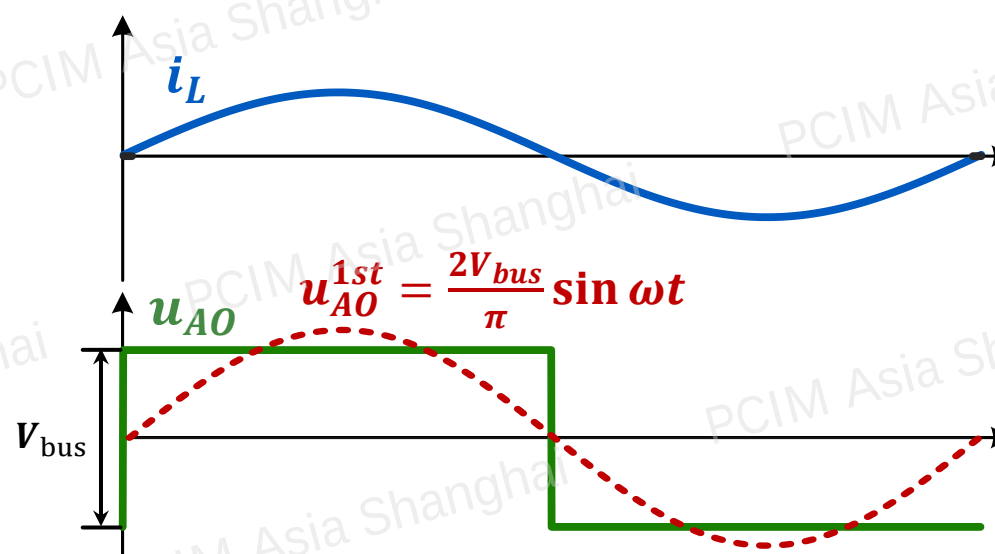


➤ Equivalent Circuit of Phase-A



Assuming:

1. $PF = 1$, and i_L^{1st} is considered;
2. No loss;

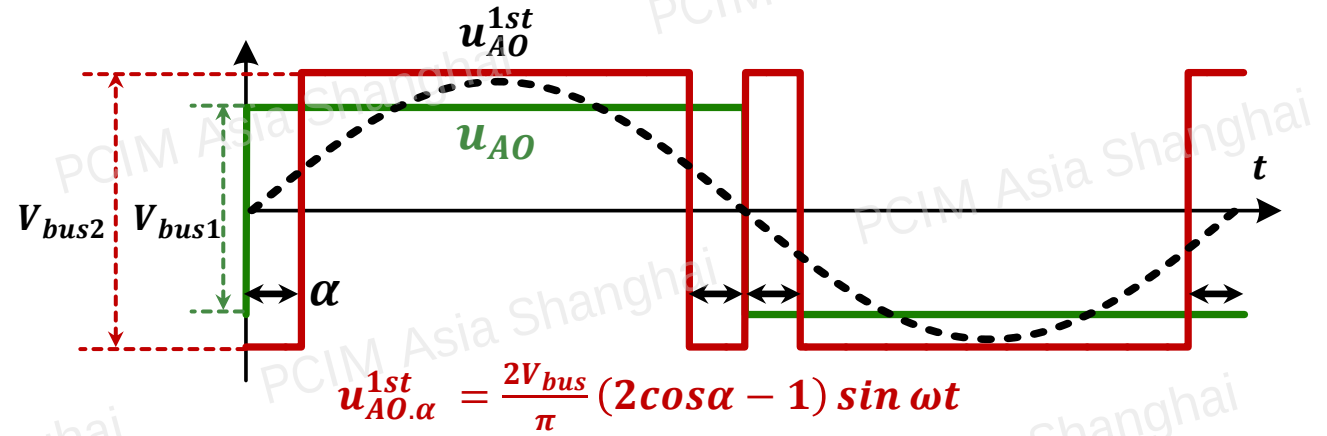
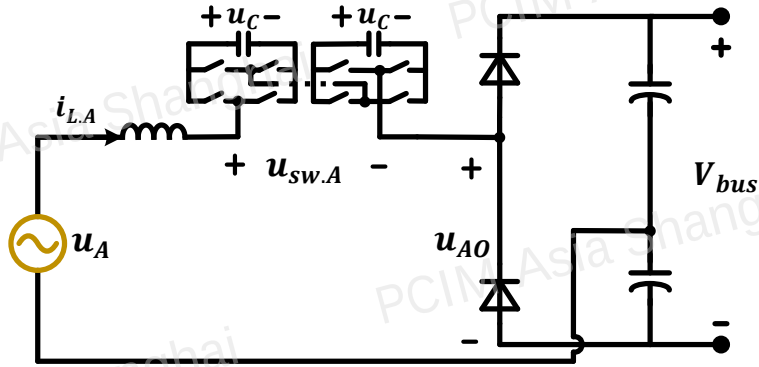


$$V_{bus} = \frac{\pi}{\sqrt{2}} U_A$$

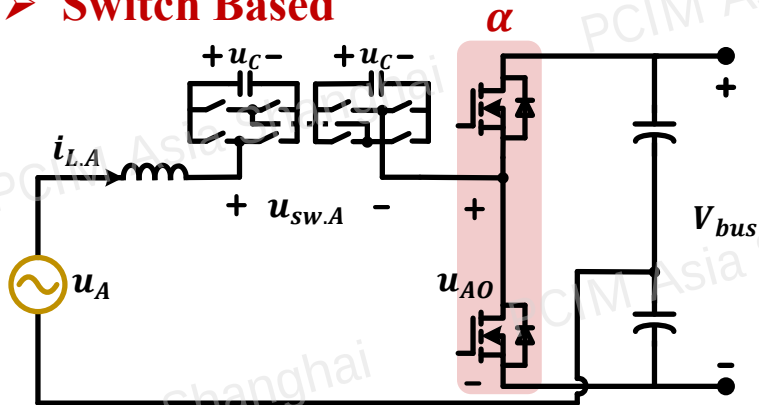
- MISN: Modular Inductive Switching Network

Regulated DC Bus Voltage for MISN Converter

➤ Diode Based ($V_o = \frac{\pi}{\sqrt{2}} U_A$)

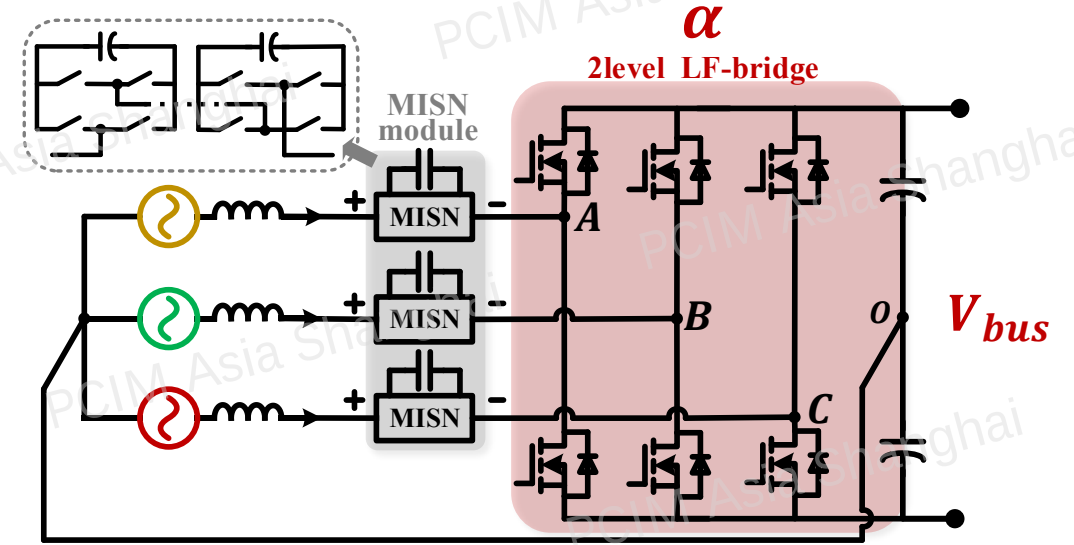
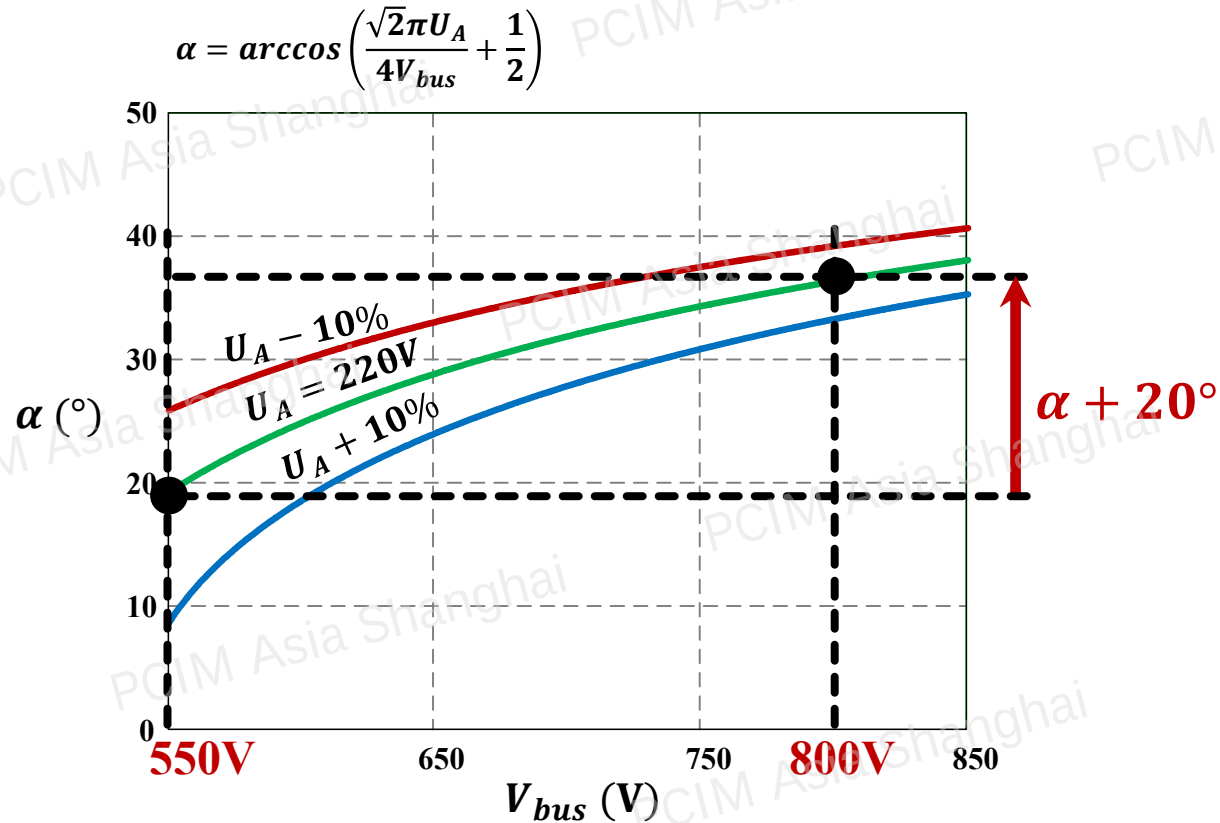


➤ Switch Based



$$\alpha = \arccos\left(\frac{\sqrt{2}\pi U_A}{4V_{bus}} + \frac{1}{2}\right)$$

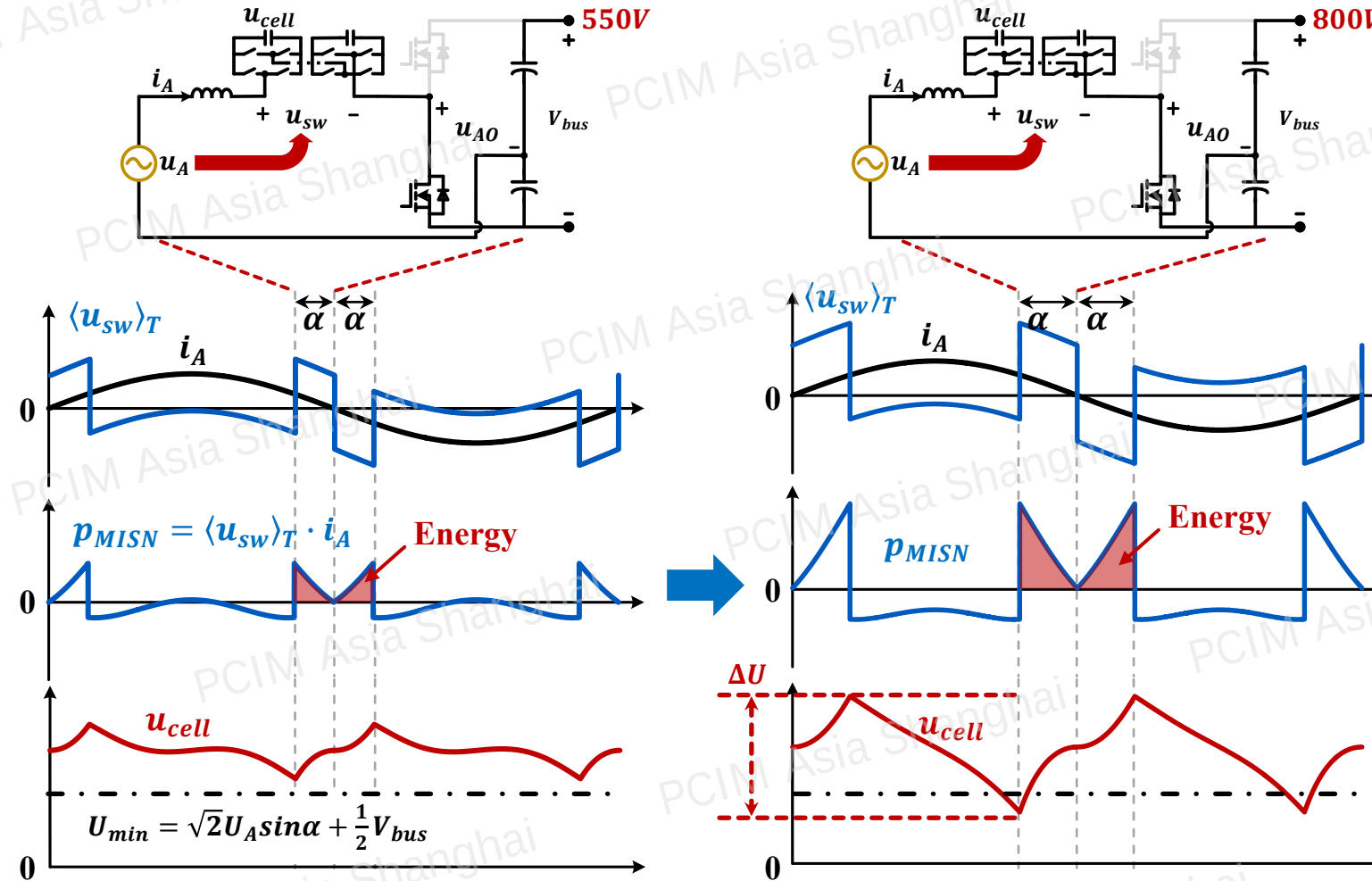
The DC Bus Voltage is Positively Correlated with α



What is the impact of the increased α ?

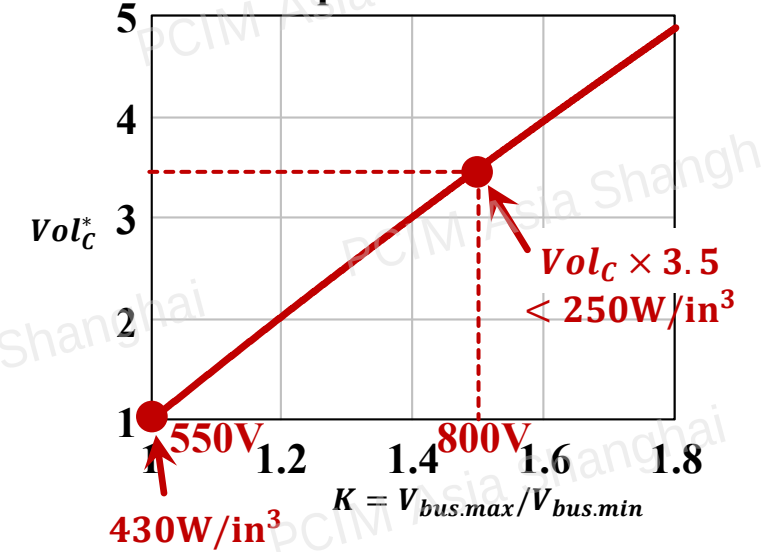
The Increased MISN Capacitors' Volume due to Large Output Voltage Range

➤ Charing Mode of MISN Module



Larger capacitance is required

➤ Mathematical model for MISN Capacitor Volume



$$Vol_C^*(K) = \frac{Vol_C(K \cdot V_{bus.min})}{Vol_C(V_{bus.min})}$$

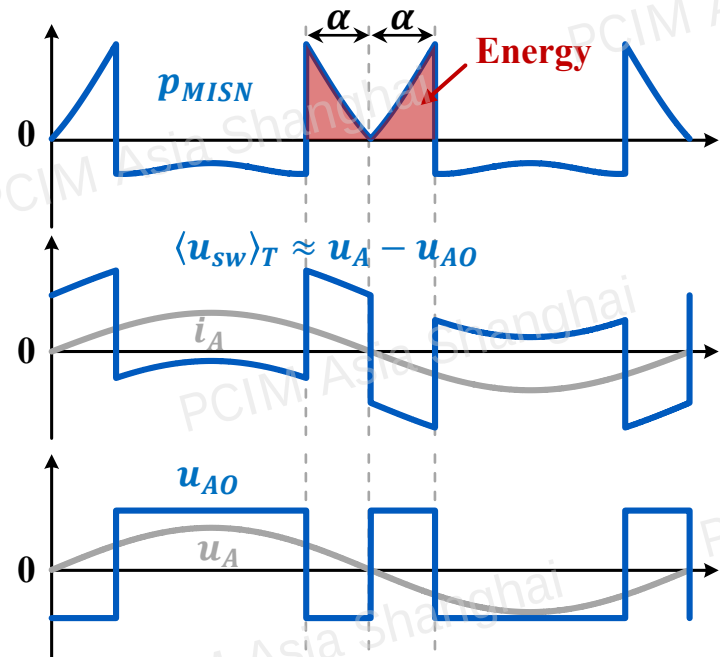
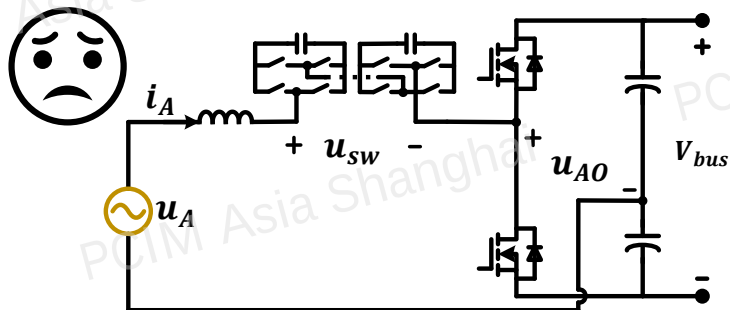
$$Vol_C = \frac{2P}{\omega E_D \Delta U} \left(2\alpha - \sin(2\alpha) - \frac{\pi(\cos\alpha - 1)}{2\cos\alpha - 1} \right)$$

$$\alpha(K) = \arccos \left(\frac{\sqrt{2}\pi U_A}{4K \cdot V_{bus.min}} + \frac{1}{2} \right)$$

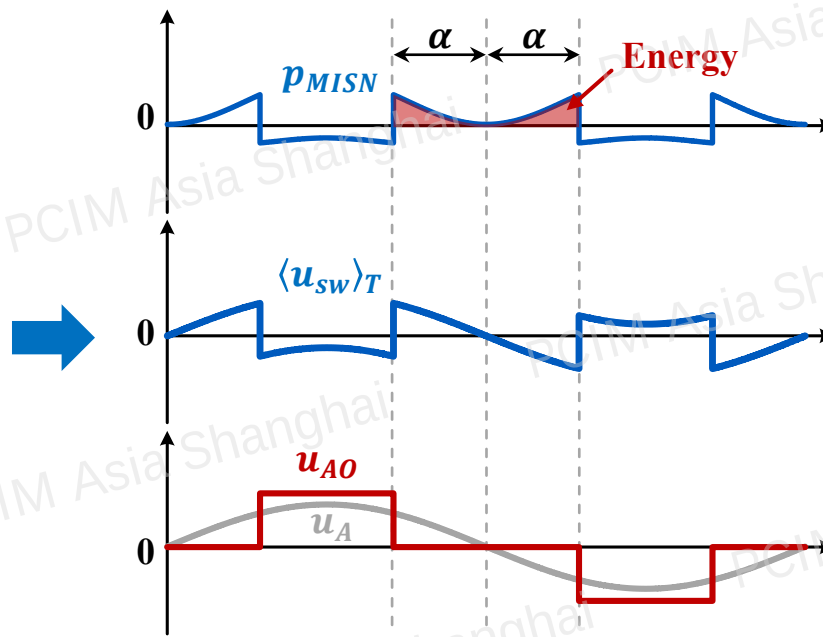
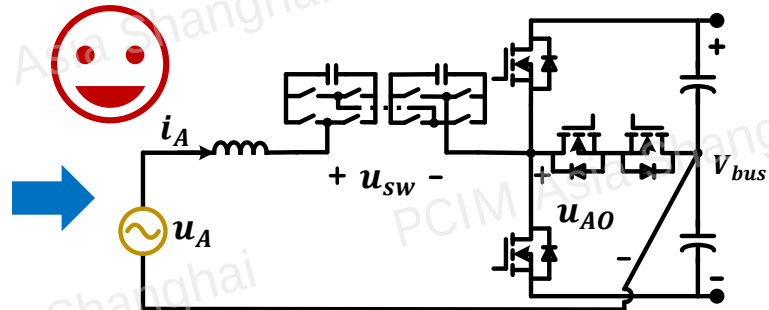
$$\Delta U = 20\%$$

Reduce Volt-second of MISN Module by 3-level LF-bridge

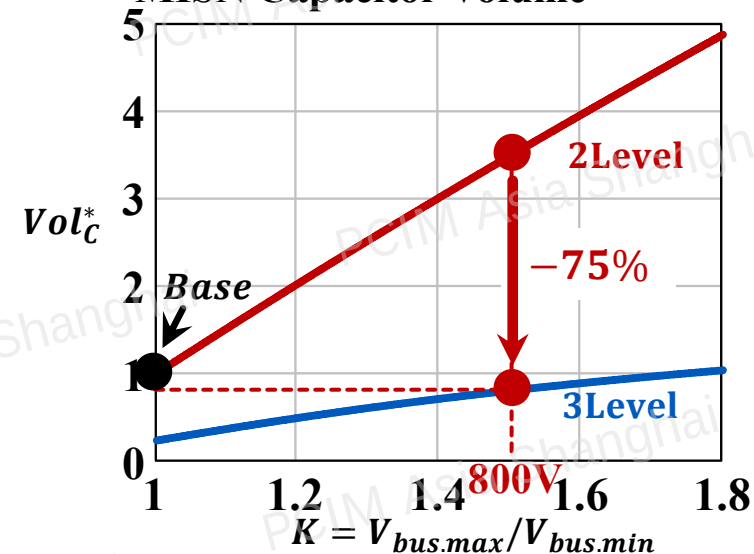
➤ 2-level LF-bridge



➤ T-type 3-level LF-bridge



➤ Mathematical model for MISN Capacitor Volume



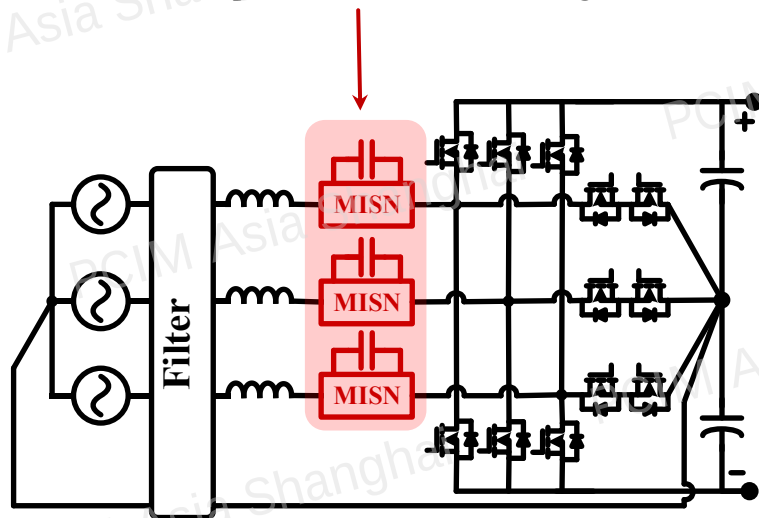
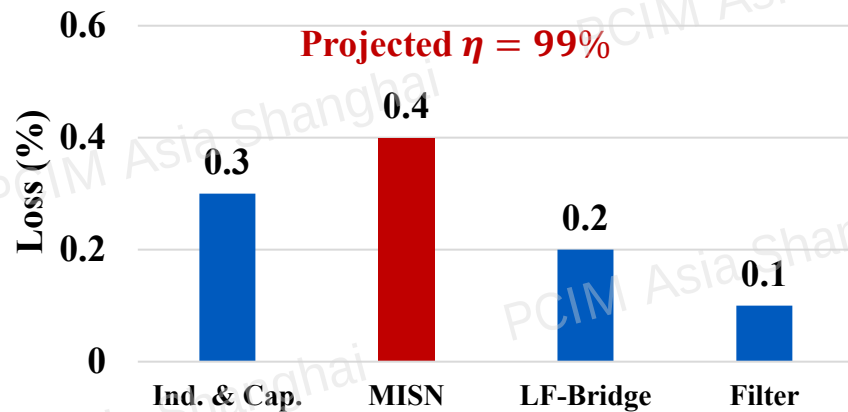
$$Vol_{C,2level}^* = \frac{Vol_{C,2level}(K \cdot V_{bus.min})}{Vol_{C,2level}(V_{bus.min})}$$

$$Vol_{C,3level}^* = \frac{Vol_{C,3level}(K \cdot V_{bus.min})}{Vol_{C,2level}(V_{bus.min})}$$

T-type 3-level LF-bridge
is adopted

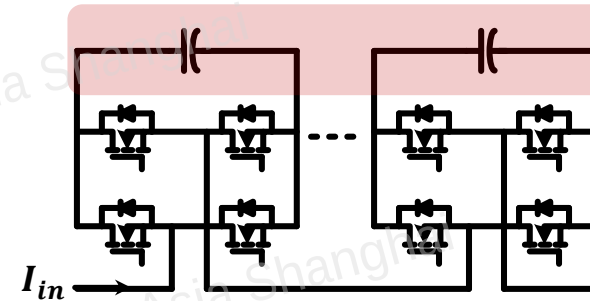
Loss Model for MISN Module (Parameters: N_c, f_s, V_{BR})

➤ The Loss Distribution at 10kW 800V_{dc}



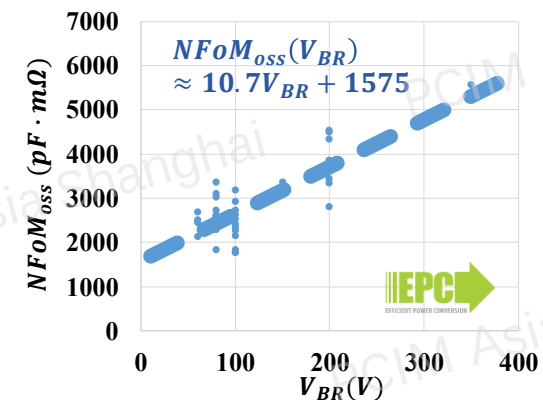
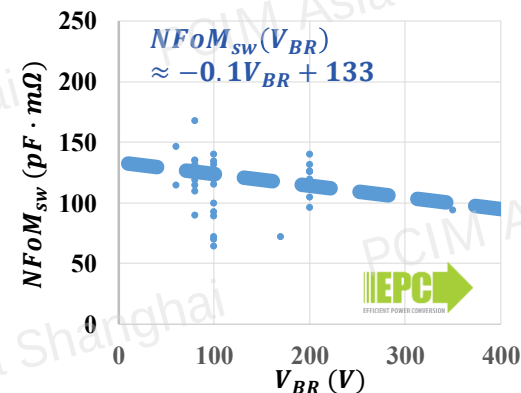
➤ Minimum Loss Model of MISN Module (GaN)

$$U_{c.total} \rightarrow 0.7 N_c V_{BR}$$



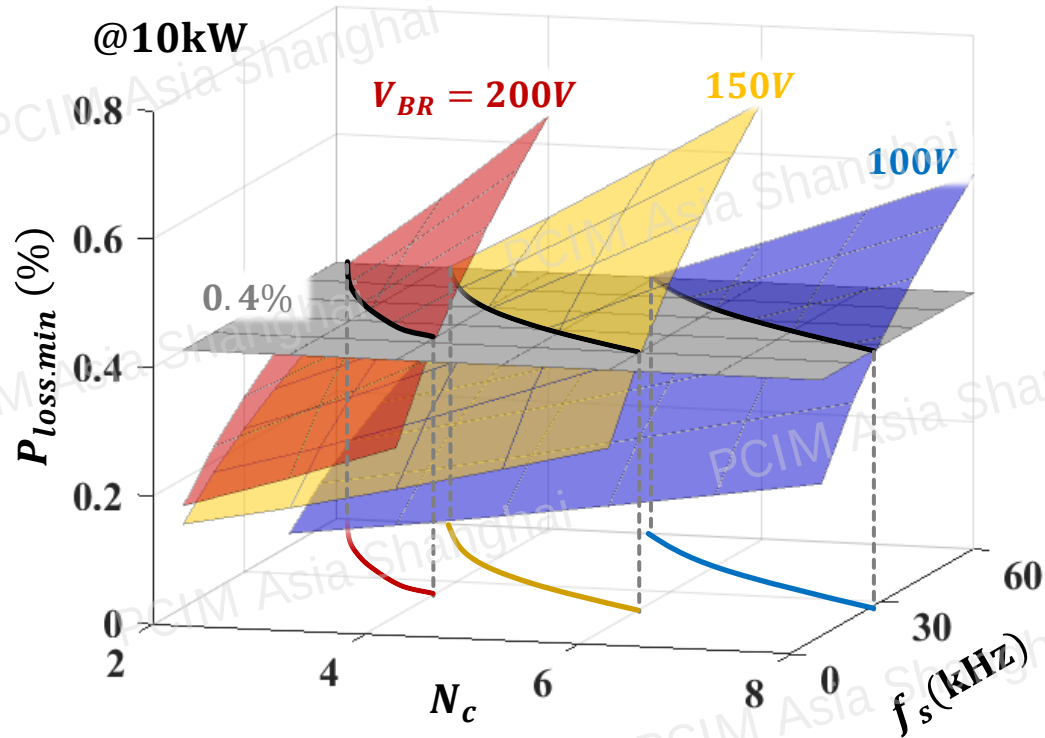
$$P_{Loss.min}(N_c, f_s, V_{BR}) = 4(U_{c.total}) I_{in} \sqrt{k_{temp} k_{dyn} (k_{sw} I_{in} NFoM_{sw} + NFoM_{oss}) f_s}$$

$$= 4(0.7 V_{BR} N_c) I_{in} \sqrt{k_{temp} k_{dyn} (k_{sw} I_{in} NFoM_{sw}(V_{BR}) + NFoM_{oss}(V_{BR})) f_s}$$

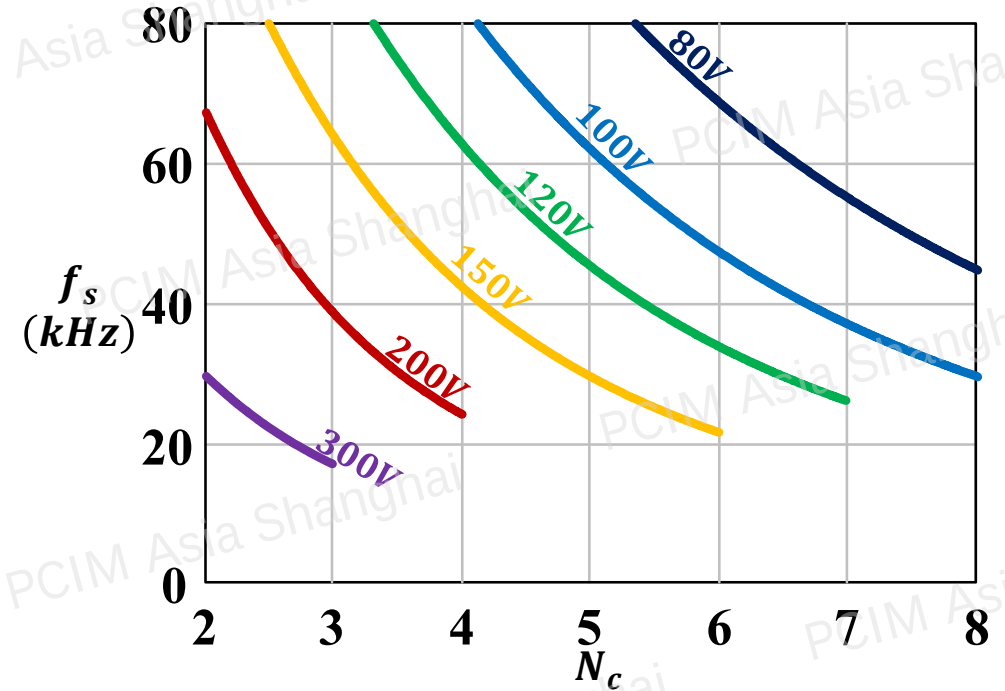


The Limitation for f_s based on the Projected Loss

➤ $P_{Loss.min} = f(N_c, f_s, V_{BR})$



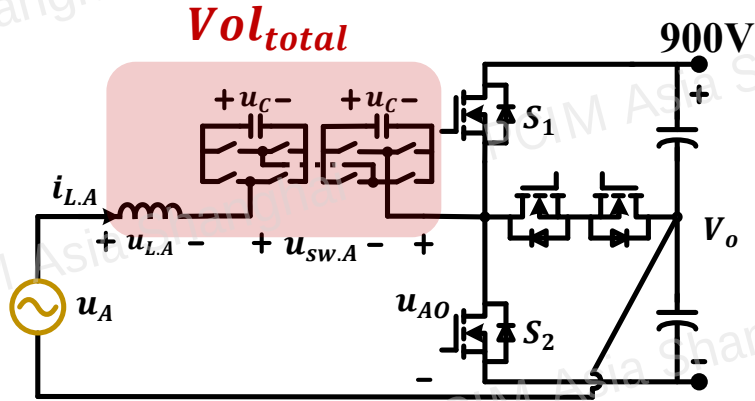
➤ The Limitation for f_s



$$f_s(N_c, V_{BR}) = \frac{1}{k_{temp} k_{dyn} (k_{sw} I_{in} N F_o M_{sw} + N F_o M_{oss})} \left(\frac{P_{loss.exp}}{4 U_{c.total}^{avg} I_{in}} \right)^2$$

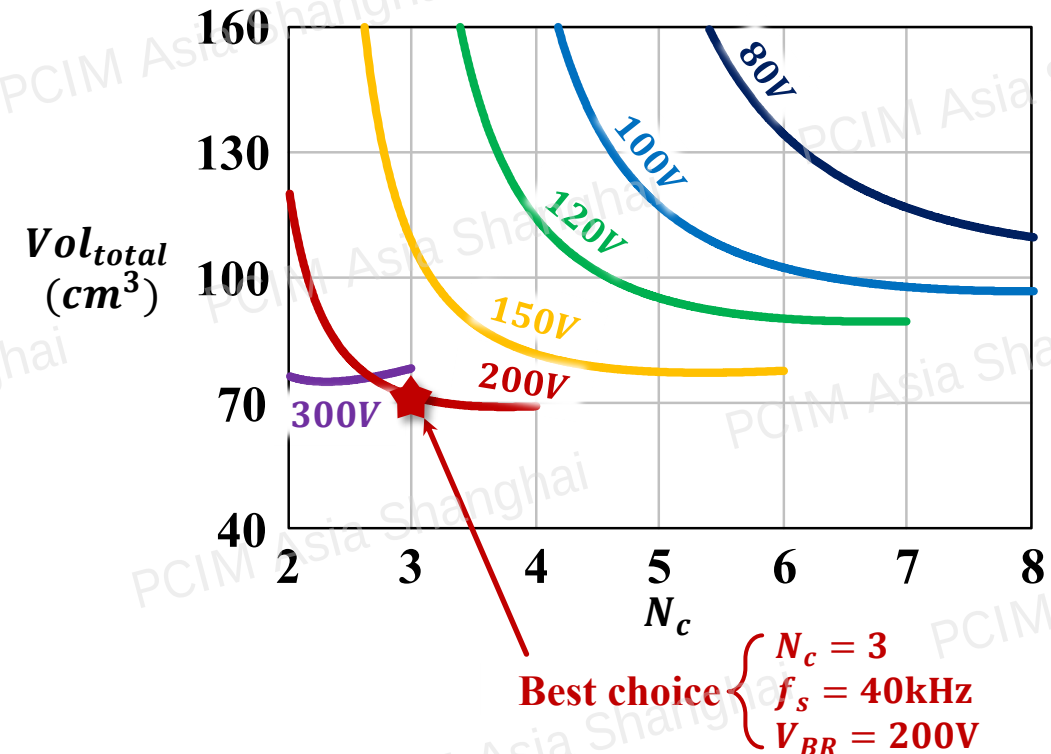
- $N_c \cdot V_{BR} \geq U_{c.total}^{valley} = \sqrt{2} U_A \sin \alpha$

Volume Optimization for 0.4% Loss Limit

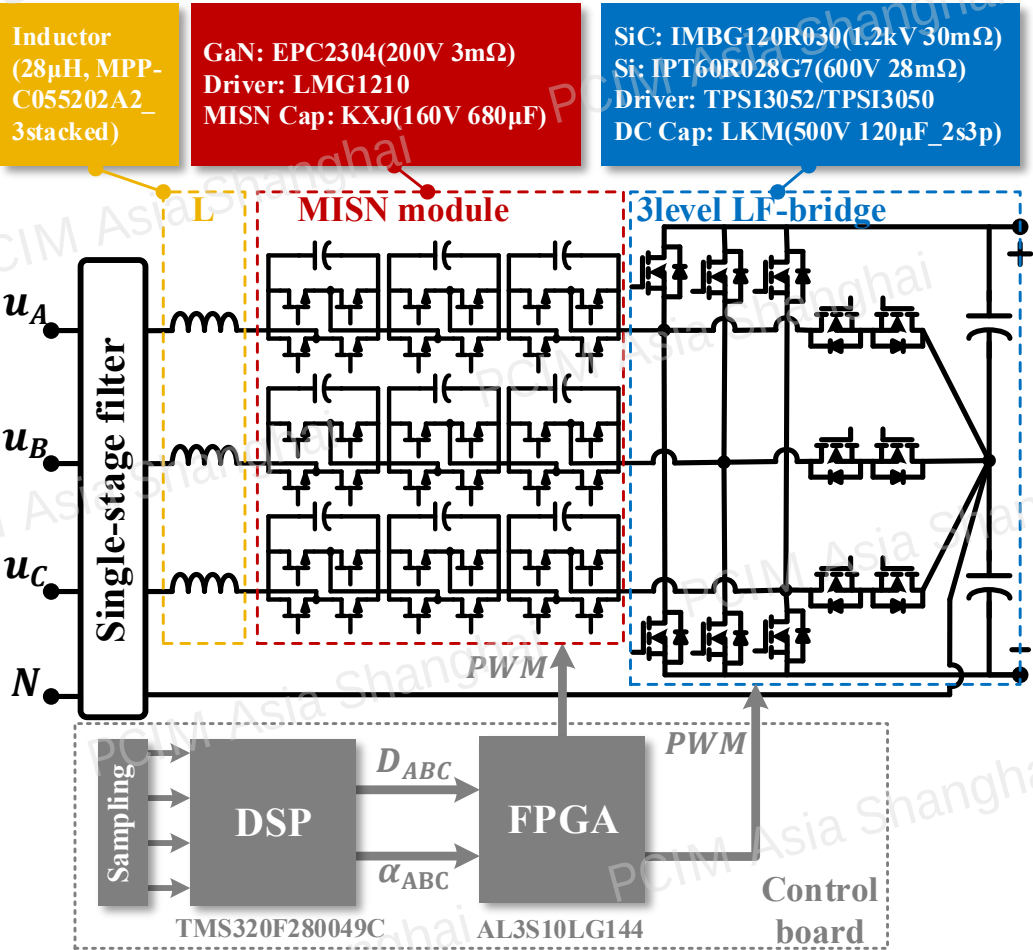


$$Vol_{total} = Vol_L + Vol_C + Vol_{cell}$$

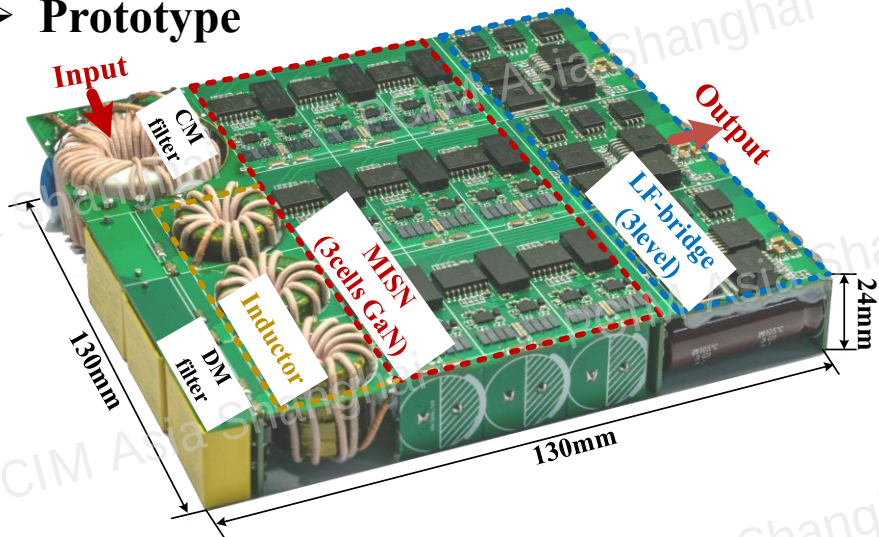
- Inductor Volume:
$$\begin{cases} L(N_c, f_s, V_{BR}) = \frac{0.7 V_{BR}}{8 N_c f_s \Delta i_{pp}} \\ (AP \text{ Method}) \\ Vol_L = k_L \left(\frac{L I_{peak} I_{RMS}}{k_w J B_m} \right)^{\frac{3}{4}} \end{cases}$$
- Capacitor Volume:
$$Vol_C(N_c, V_{BR}) = \frac{\frac{1}{2} (1.2 C_{eq.min}) (V_{BR})^2}{E_D} N_c$$
- MISN Cell Volume:
$$Vol_{cell} = K \cdot N_c$$



➤ Schematic Diagram



➤ Prototype



Power Density: 400W/in³ (~25kW/L)

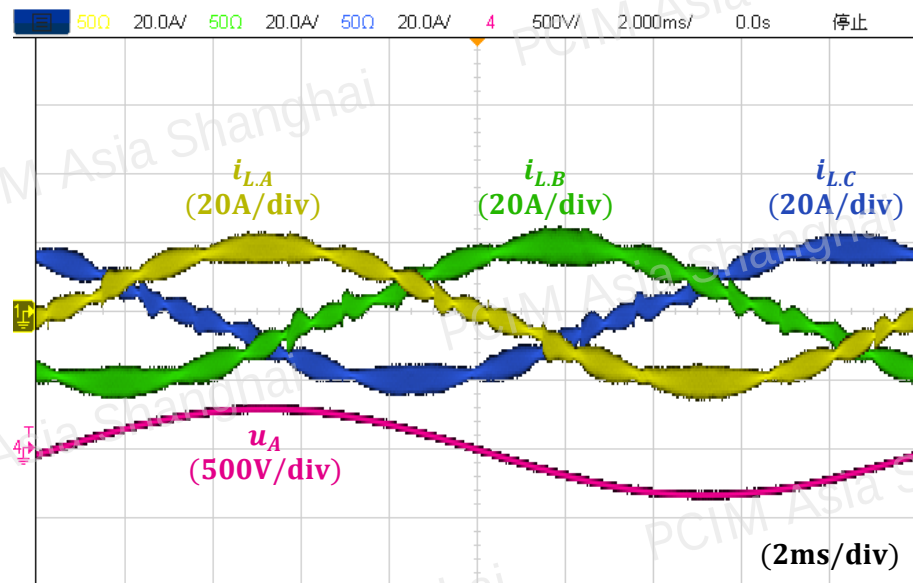
Parameter	Value
Power	10kW
Input Phase Voltage	220V _{RMS} ± 10%
DC Bus Voltage	Typical: 800V 550V~900V
MISN Voltage	3 × 120V
Frequency (MISN)	40kHz

Sponsor:

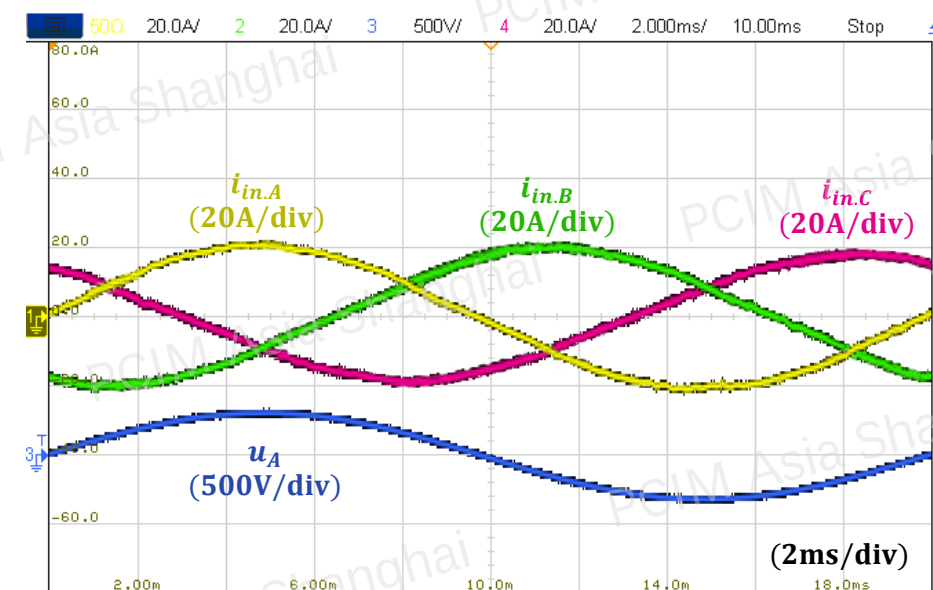


The Waveforms of Currents at Full-load

➤ Three-phase Inductor Currents

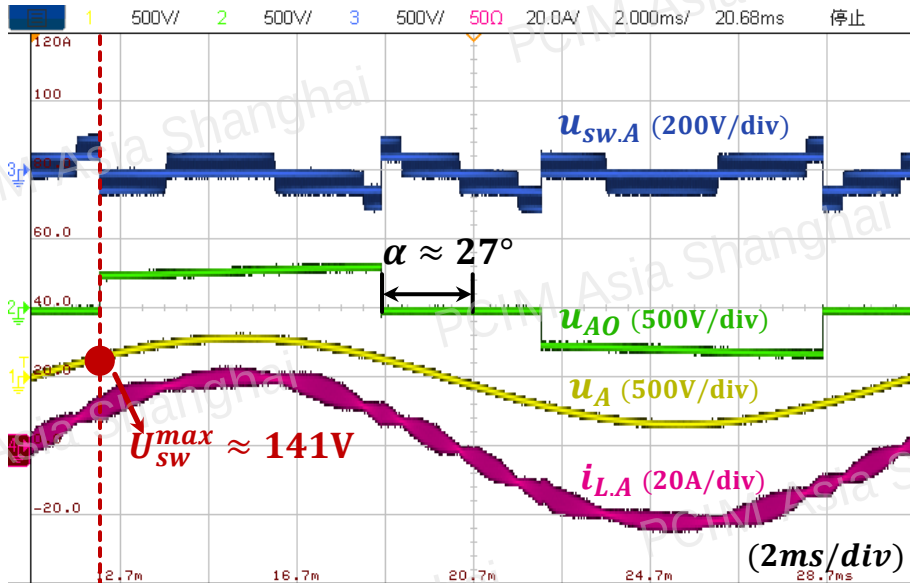


➤ Three-phase Input Currents

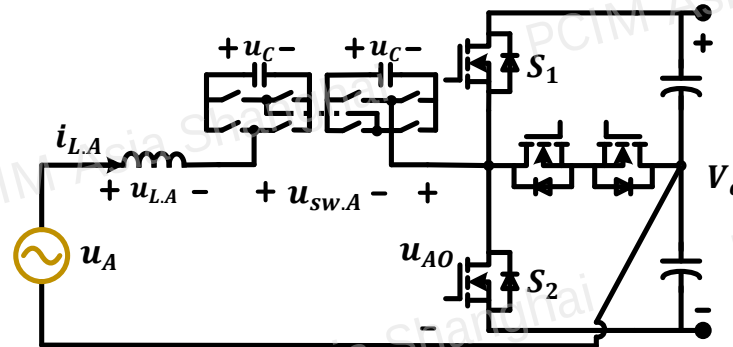
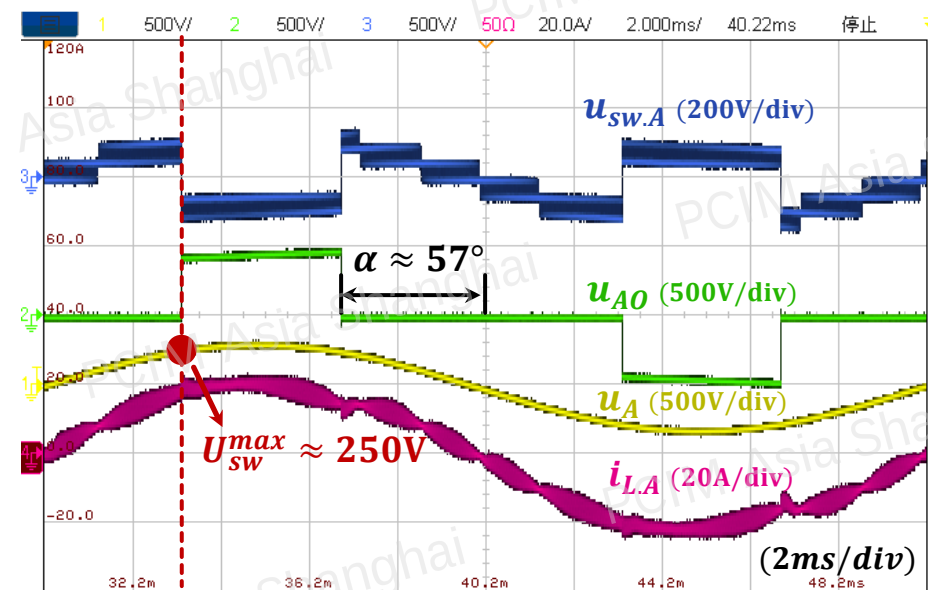


The Waveforms of AC-side Voltages and MISN Voltage Stress

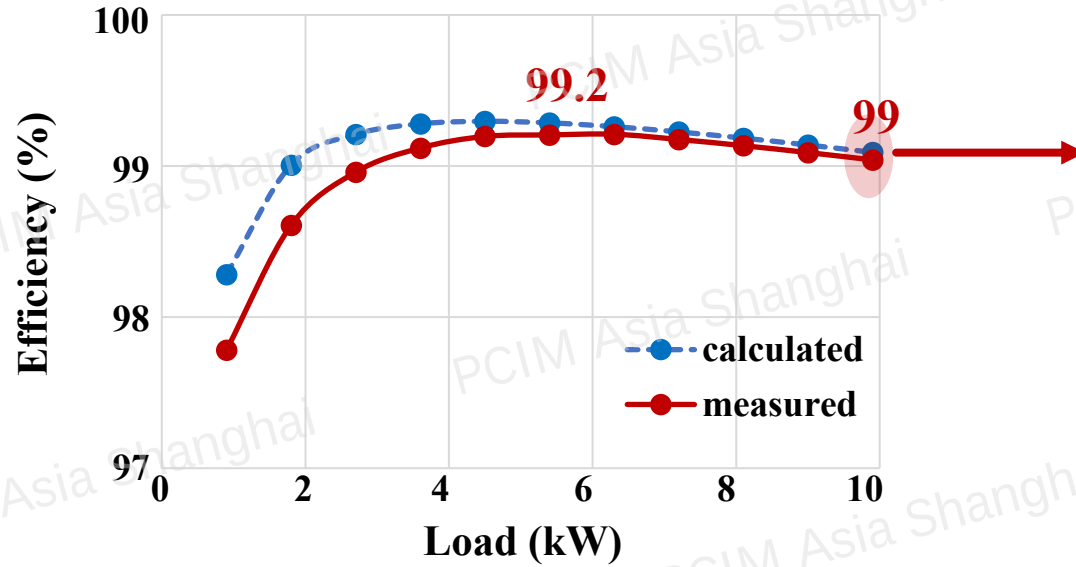
➤ $V_{bus} = 550V$



➤ $V_{bus} = 800V$

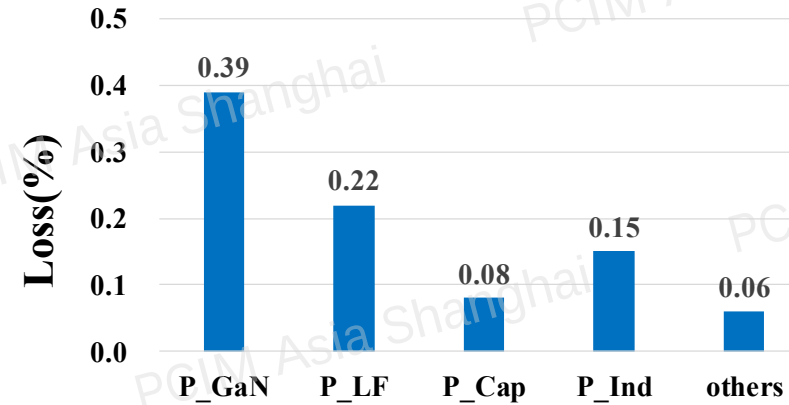


Efficiency for the Designed MISN Converter

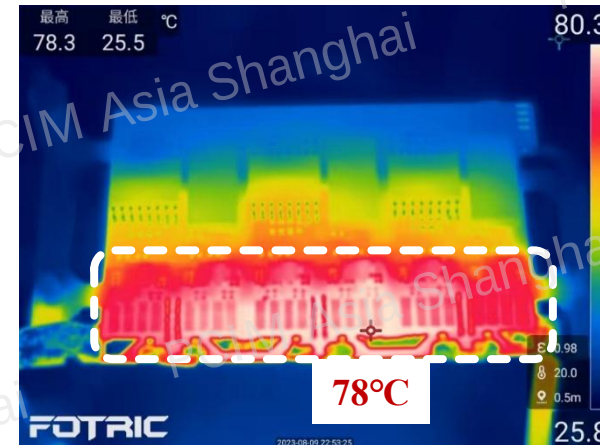


- $380V_{RMS} \rightarrow 800V_{dc}$
- Test condition: 5min/point
- exclude auxiliary loss

➤ Loss breakdown for 10kW



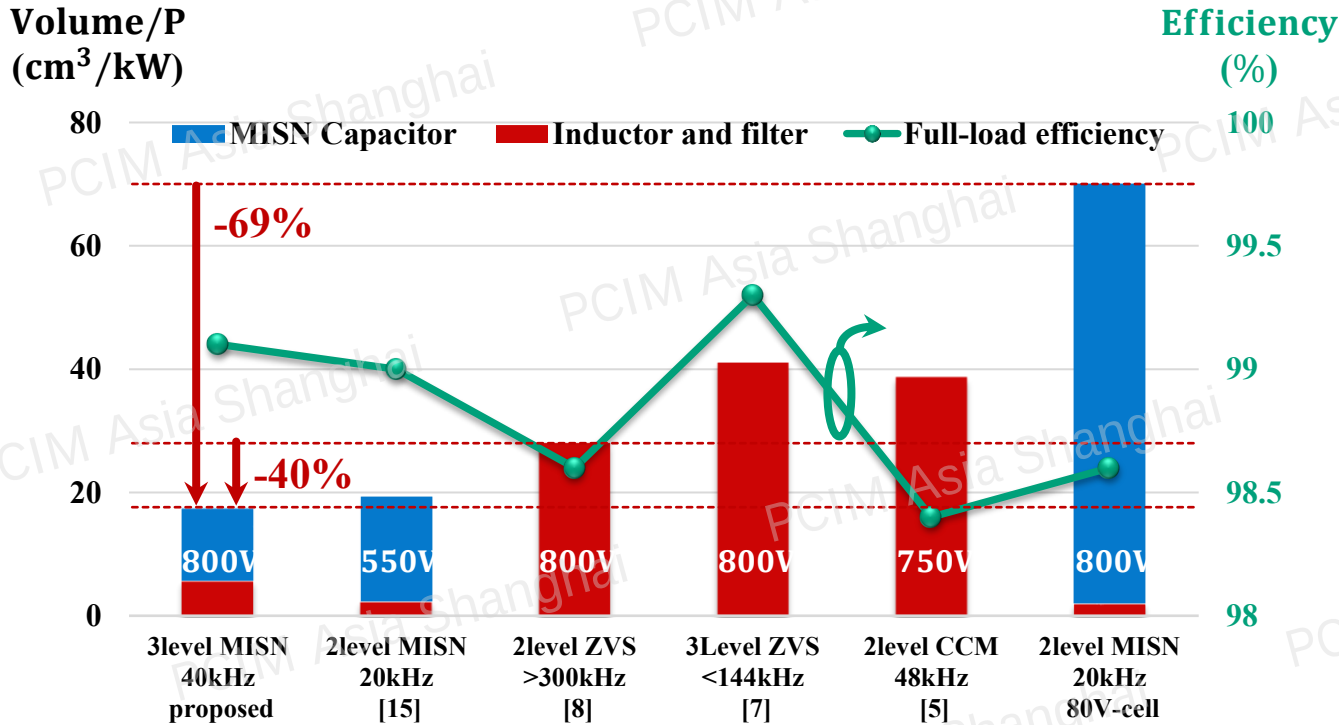
➤ The Temperature at Full Load



GaN & Driver

wind speed: ~3m/s

Comparison for different schematics in the aspects of components' volumes and full load efficiencies.

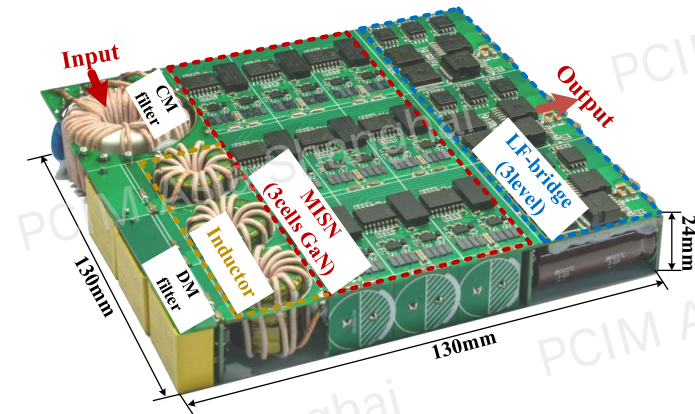


Ref	Type	Spec.	fs	THD	Eff	kW/L	Cost
[5]	2LB6 CCM	22kW 650~750V	48kHz	3.2%	98.4%	8	Low
[8]	2LB6 CRM	25kW 650~800V	300~530k Hz	2%	98.9%	11	Mid
[7]	T-type TCM	6kW 650~800V	140kHz	-	99.3%	11.8	Mid
[15]	MISN 2level LF	10kW 550V	20kHz	2.5%	99%	26	High
This	MISN 3level LF	10kW 550V	40kHz	3%	99%	25	High

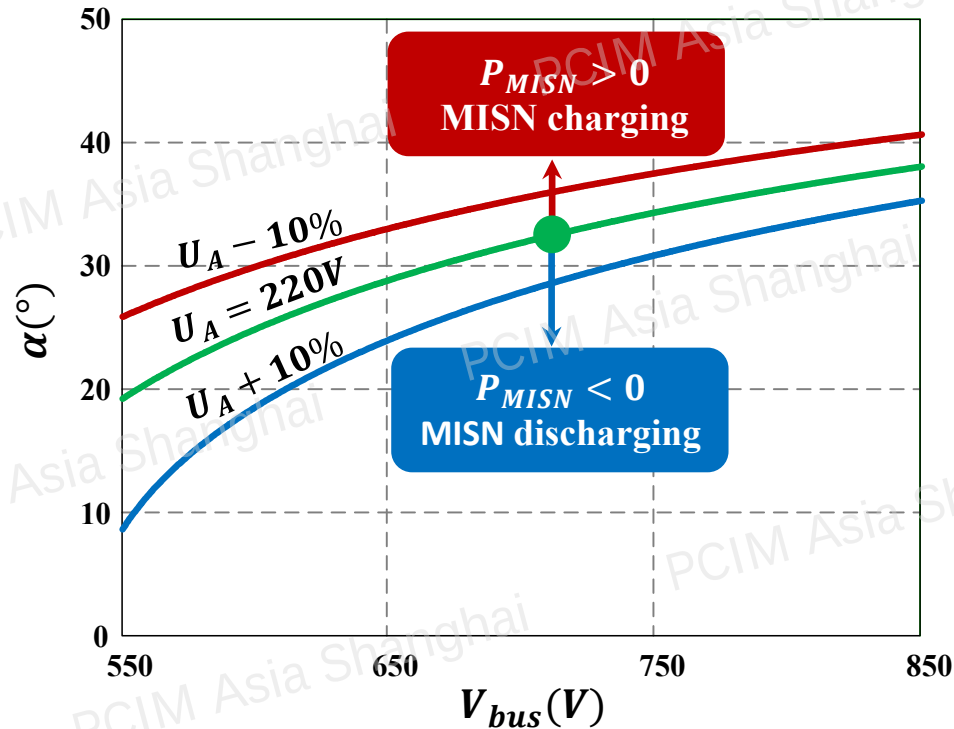
- Passive components' volumes are reduced more than 40%
- More than 99% Efficiency is achieved

- To address the issue of reduced power density in three-phase MISN converters under a high DC bus voltage, the impact of bus voltage on the buffer energy of the MISN was modeled and analyzed. **This revealed the critical influence of the line-frequency rectifier bridge on the MISN capacitor size.**
- A topology optimization method was proposed using a T-type three-level line-frequency rectifier bridge. Compared to a two-level design, **this reduced the required MISN capacitor volume by 75% at a 800V bus voltage.**
- For the multi-variable optimization challenge of the MISN converter, **a minimum loss model and a volume model for key components were established.** A hierarchical optimization design method was subsequently proposed to fully exploit the potential for efficiency and power density.
- A prototype was built and tested with 800V DC bus. It achieved a **power density of 400W/in³** and a **peak efficiency of 99.2%.**

Thanks!



The Principle for MISN Voltage Control



$$\alpha = \arccos\left(\frac{\sqrt{2}\pi U_A}{4V_{bus}} + \frac{1}{2}\right)$$

$$P_{MISN} = \frac{1}{2\pi} \int_0^{2\pi} p_{MISN} d\omega t = \frac{\sqrt{2}I_L}{\pi} (\sqrt{2}\pi U_A - 2V_{bus})$$

➤ In the curve

$P_{MISN} = 0$, Power balance

➤ Above the curve

$P_{MISN} > 0$, Charging mode

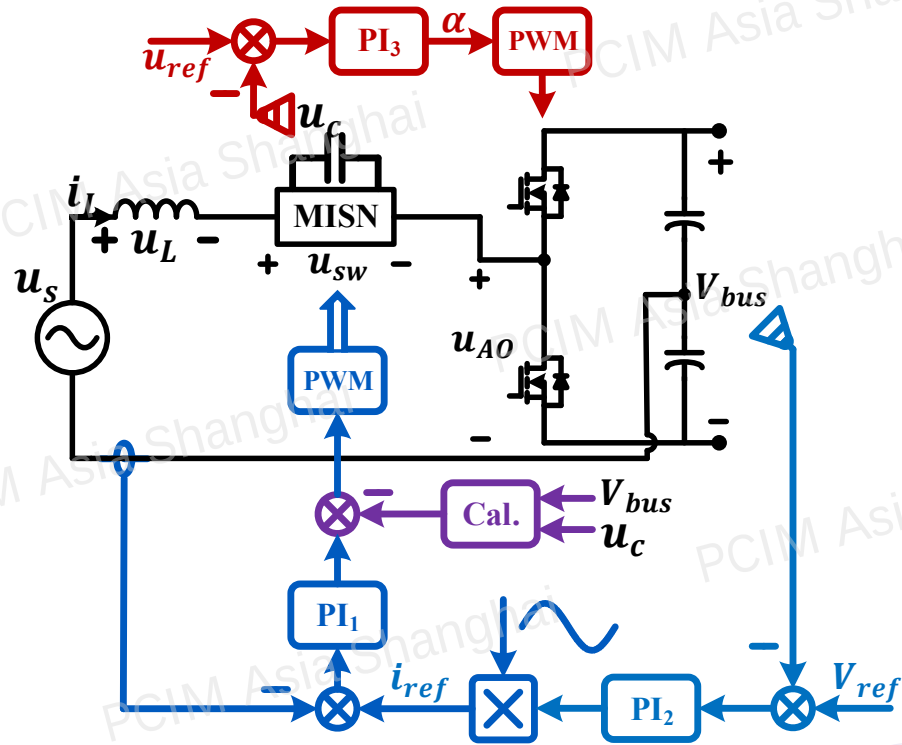
➤ Below the curve

$P_{MISN} < 0$, Discharging mode

Utilized for MISN
voltage Control

Three-loop Control Strategy for MISN-PFC

➤ The Control Strategy of Phase-A



$$\Delta PI(t) = \frac{v_{bus}(t)}{2N \cdot u_c(t)}$$

